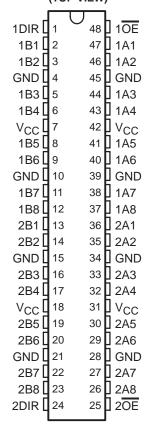
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- State-of-the-Art Advanced BiCMOS
 Technology (ABT) Widebus™ Design for
 2.5-V and 3.3-V Operation and Low
 Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- High Drive (-32/64 mA at 3.3-V V_{CC})
- I_{off} and Power-Up 3-State Support Hot Insertion
- Use Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Flow-Through Architecture Facilitates
 Printed Circuit Board Layout
- Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

description

The 'ALVTH16245 devices are 16-bit (dual-octal) noninverting 3-state transceivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

SN54ALVTH16245 . . . WD PACKAGE SN74ALVTH16245 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.2 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



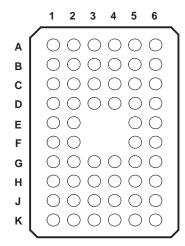
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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SN74ALVTH16245 . . . GQL PACKAGE (TOP VIEW)



terminal assignments

	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1OE
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	Vcc	Vcc	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
Е	1B8	1B7			1A7	1A8
F	2B1	2B2		_	2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
Н	2B5	2B6	Vcc	Vcc	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
K	2DIR	NC	NC	NC	NC	2OE

NC - No internal connection

ORDERING INFORMATION

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP – DL	Tape and reel	SN74ALVTH16245DLR	ALVTH16245
400C to 050C	TSSOP – DGG	Tape and reel	SN74ALVTH16245GR	ALVTH16245
-40°C to 85°C	TVSOP – DGV	Tape and reel	SN74ALVTH16245VR	VT245
	VFBGA – GQL	Tape and reel	SN74ALVTH16245QR	
–55°C to 125°C	CFP – WD	Tube	SNJ54ALVTH16245WD	SNJ54ALVTH16245WD

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

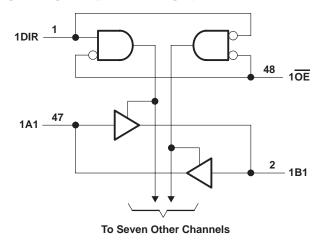
FUNCTION TABLE (each 8-bit section)

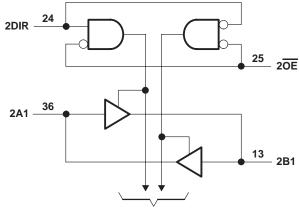
INP	UTS	0050471011
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation



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logic diagram (positive logic)





To Seven Other Channels

Pin numbers shown are for the DGG, DGV, DL, and WD packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}
Input voltage range, V _I (see Note 1)
Voltage range applied to any output in the high or power-off state, V _O (see Note 1)0.5 V to 7 V
Output current in the low state, IO: SN54ALVTH16245
SN74ALVTH16245 128 mA
Output current in the high state, I _O : SN54ALVTH16245 –48 mA
SN74ALVTH16245 –64 mA
Input clamp current, I_{IK} ($V_I < 0$)
Output clamp current, I_{OK} ($V_O < 0$)
Package thermal impedance, θ _{JA} (see Note 2): DGG package
DGV package 58°C/W
DL package 63°C/W
GQL package 42°C/W
Storage temperature range, T _{stg} –65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

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recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 2.5 V \pm 0.2 V (see Note 3)

			SN54	ALVTH1	6245	SN74	ALVTH1	6245	
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VCC	Supply voltage		2.3		2.7	2.3		2.7	V
VIH	High-level input voltage		1.7		7	1.7			V
V _{IL}	Low-level input voltage			Ś	0.7			0.7	V
VI	Input voltage		0	V _C C	5.5	0	VCC	5.5	V
loн	High-level output current			1	-6			-8	mA
	Low-level output current			2	6			8	4
lor	Low-level output current; current duty cycle ≤ 5	50%; f≥1 kHz	Š	5	18			24	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 3.3 V \pm 0.3 V (see Note 3)

			SN54ALVTH16245			SN74ALVTH16245			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNII
Vcc	Supply voltage	Supply voltage			3.6	3		3.6	V
VIH	High-level input voltage		2		7	2			V
V _{IL}	Low-level input voltage			Š	0.8			8.0	V
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
IOH	High-level output current			7	-24			-32	mA
	Low-level output current			2	24			32	A
loL	Low-level output current; current duty cycle ≤	50%; f ≥ 1 kHz	Š	5	48			64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
T _A	Operating free-air temperature	_	-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

				SN54	ALVTH1	6245	SN74	ALVTH1	6245	LINUT	
P/	ARAMETER	TEST CO	ONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT	
٧ıK		$V_{CC} = 2.3 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OH} = -100 μA	VCC-0	.2		VCC-0	.2			
Vон		V 22V	$I_{OH} = -6 \text{ mA}$	1.8						V	
		V _{CC} = 2.3 V	$I_{OH} = -8 \text{ mA}$				1.8				
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OL} = 100 \mu A$			0.2			0.2		
			$I_{OL} = 6 \text{ mA}$			0.4					
VOL		V _{CC} = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V	
		VCC = 2.3 V	$I_{OL} = 18 \text{ mA}$			0.5					
			$I_{OL} = 24 \text{ mA}$			4			0.5		
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND		3	±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V		4	10			10		
lį			V _I = 5.5 V		V.	20			20	μΑ	
	A or B ports	V _{CC} = 2.7 V	AI = ACC		50	1			1		
			V _I = 0		5	-5			- 5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	Q	·				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	V _I = 0.7 V		115			115		μΑ	
IBHH§		$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V		-10			-10		μΑ	
IBHLO	,¶	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300			300			μΑ	
IBHHC) [#]	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ	
{IEX}		$V{CC} = 2.3 \text{ V},$	V _O = 5.5 V			125			125	μΑ	
IOZ(PI	J/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \frac{0.5}{\text{OE}} \text{ V}$ V _I = GND or V _{CC} , $\overline{\text{OE}}$ =	to V _{CC} , don't care			±100			±100	μΑ	
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1	mA	
ICC		I _O = 0, V _I = V _{CC} or GND	Outputs low		2.3	4.5		2.3	4.5		
			Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3.5			3.5		pF	
C _{io}		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		8			8		pF	

 $^{^{\}dagger}$ All typical values are at V_{CC} = 2.5 V, T_A = 25°C.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

[¶] An external driver must source at least I_{BHLO} to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54	ALVTH1	6245	SN74	ALVTH1	6245		
PAI	RAMETER	IESI C	CONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT	
٧ıK		$V_{CC} = 3 V$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0	.2		VCC-0	.2			
VOH		V 2 V	$I_{OH} = -24 \text{ mA}$	2						V	
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2				
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2		
			I _{OL} = 16 mA						0.4		
V			$I_{OL} = 24 \text{ mA}$			0.5				V	
VOL		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V	
			$I_{OL} = 48 \text{ mA}$			0.55					
			$I_{OL} = 64 \text{ mA}$			2			0.55		
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		3	±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		PA	10			10		
lį			V _I = 5.5 V		7	20			20	μΑ	
		V _{CC} = 3.6 V	$V_I = V_{CC}$		2	1			1		
			V _I = 0		5	-5			-5		
I _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	Q					±100	μΑ	
I _{BHL} ‡		$V_{CC} = 3 V$,	V _I = 0.8 V	75			75			μΑ	
IBHH§		$V_{CC} = 3 V$	V _I = 2 V	-75			-75			μΑ	
IBHLO	Ī	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	500			500			μΑ	
IBHHO [#]	#	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	-500			-500			μΑ	
{IEX}		$V{CC} = 3 V$	$V_0 = 5.5 \text{ V}$			125			125	μΑ	
IOZ(PU	/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = \underline{0.5}$	V to V _{CC} , = don't care			±100			±100	μΑ	
		V _{CC} = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1		
ICC		$I_{O} = 0$,	Outputs low		3.2	5		3.2	5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled		0.07	0.1		0.07	0.1		
ΔlCC□		V _{CC} = 3 V to 3.6 V, On Other inputs at V _{CC} or			_	0.2		_	0.2	mA	
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0		3.5			3.5		pF	
C _{io}		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		8			8		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{II} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

[¶] An external driver must source at least I_{BHLO} to switch this node from low to high.

[#]An external driver must sink at least IBHHO to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

[☐] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

	FROM	ТО	SN54ALVTH16245		SN74AL\		
PARAMETER	ER (INPUT) (OUTPUT)		MIN	MAX	MIN	MAX	UNIT
^t PLH	A on B	D on A	0.5	3.6	0.5	3.6	
t _{PHL}	A or B	B or A	0.5	3.4	0.5	3.4	ns
^t PZH	OE	A on D	1.5	4.9	1.5	4.9	
^t PZL	OE OE	A or B	1.5	4	1	4	ns
^t PHZ	OE	A or D	1.5	4.9	1.5	4.9	20
^t PLZ]	A or B	Q Ý	4.2	1	4.2	ns

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETER	FROM	I	SN54ALVTH16245		SN74AL\		
PARAMETER	(INPUT)		MIN	MAX	MIN	MAX	UNIT
^t PLH	A - :: B	B or A	0.5	3.1	0.5	3.1	
^t PHL	A or B		0.5	2.9	0.5	2.9	ns
^t PZH	OE	A D	1	4.2	1	4.2	
tPZL	OE OE	A or B	1.5	3.5	1	3.5	ns
^t PHZ	- ŌĒ	A or D	1.5	5.3	1.5	5.3	
t _{PLZ}		A or B	1.5	5	1.5	5	ns

skew

 t_{ps} (pin or transition skew), $t_{ps} = |t_{PHL} - t_{PHL}|$

PS			
	V _{CC} = 2.5 V	V _{CC} = 3.3 V	LINUT
	TYP	TYP	UNIT
t _{ps} max	438	118	ps

t_{OST} = $|t_{p\Phi m} - t_{p\Phi n}|$, where Φ is any edge transition (high to low or low to high) measured between any two outputs (m or n) within any given device (see Note 4)

		V _{CC} = 2.5 V	V _{CC} = 3.3 V	LINUT	
		TYP	TYP	UNIT	
	A–B	227	248		
tost	B–A	223	243	ps	

NOTE 4: One output switching, T_A = 25°C

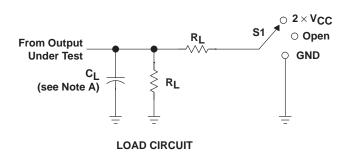
t_{OSHL}/t_{OSLH} (common edge skew), $t_{OSHL} = |t_{PHL} max - t_{PHL} min|$ (output skew for low-to-high transitions), and $t_{OSLH} = |t_{PLH} max - t_{PLH} min|$ (output skew for high-to-low transitions) (see Note 4)

		$V_{CC} = 2.5 V$	$V_{CC} = 3.3 \text{ V}$	
		TYP	TYP	UNIT
^t OSLH		210	145	
^t OSHL	A–B	243	351	ps
^t OSLH	B-A	207	136	20
^t OSHL	D-A	238	350	ps

NOTE 4: One output switching, $T_A = 25^{\circ}C$

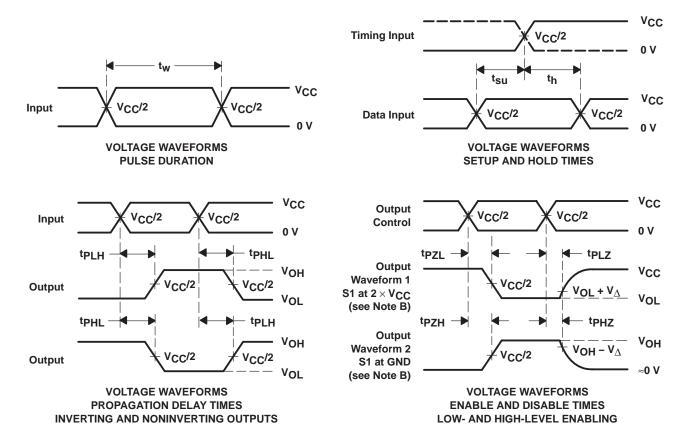


PARAMETER MEASUREMENT INFORMATION



TEST	S 1
tPLH/tPHL	Open
tPLZ/tPZL	2×V _{CC}
tPHZ/tPZH	GND

VCC	CL	RL	${f v}_{\Delta}$
2.5 V ±0.2 V	30 pF	500 Ω	0.15 V
3.3 V ±0.3 V	50 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. tpLH and tpHL are the same as tpd.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
74ALVTH16245DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
74ALVTH16245DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
74ALVTH16245GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
74ALVTH16245GRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
74ALVTH16245VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT245	Samples
74ALVTH16245VRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT245	Samples
74ALVTH16245ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VT245	Samples
SN74ALVTH16245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
SN74ALVTH16245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
SN74ALVTH16245GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16245	Samples
SN74ALVTH16245KR	OBSOLETE	E BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	-40 to 85	VT245	
SN74ALVTH16245VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT245	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

11-Apr-2013

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74ALVTH16245ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
SN74ALVTH16245DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74ALVTH16245GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74ALVTH16245VR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1

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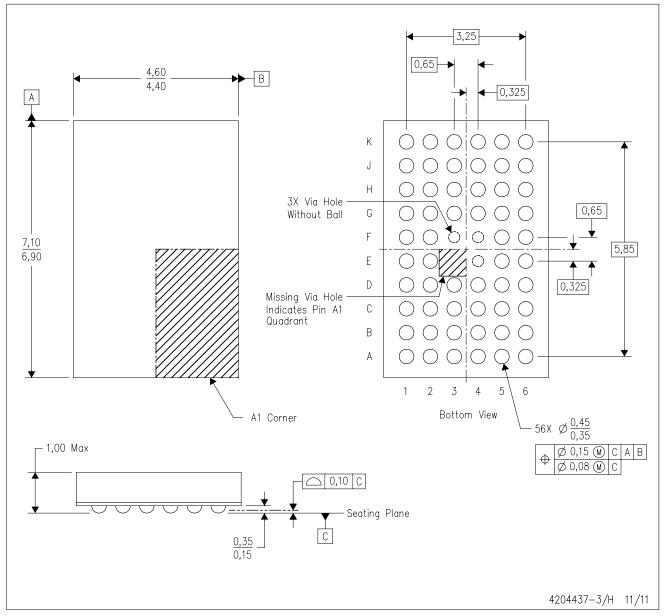


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74ALVTH16245ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	333.2	345.9	28.6
SN74ALVTH16245DLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74ALVTH16245GR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74ALVTH16245VR	TVSOP	DGV	48	2000	367.0	367.0	38.0

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

MicroStar Junior is a trademark of Texas Instruments



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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